NSN 5961-00-424-9797

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Inclosure Material:
Metal
Overall Length:
Between 0.325 inches and 0.460 inches
Overall Diameter:
0.648 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.687 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 8.0
breakdown voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current
Power Rating Per Characteristic:
50.0 watts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 tab, solder lug
Specification Data:
80131-release5228 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:

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